

HA12240FP

Bus Interface Driver/Receiver IC

REJ03F0095-0100Z

Rev.1.0

Dec.01.2003

Description

The HA12240FP is developed to be used as a bus interface driver/receiver IC in automotive audio equipment controllers. It implements a two-wire serial bus.

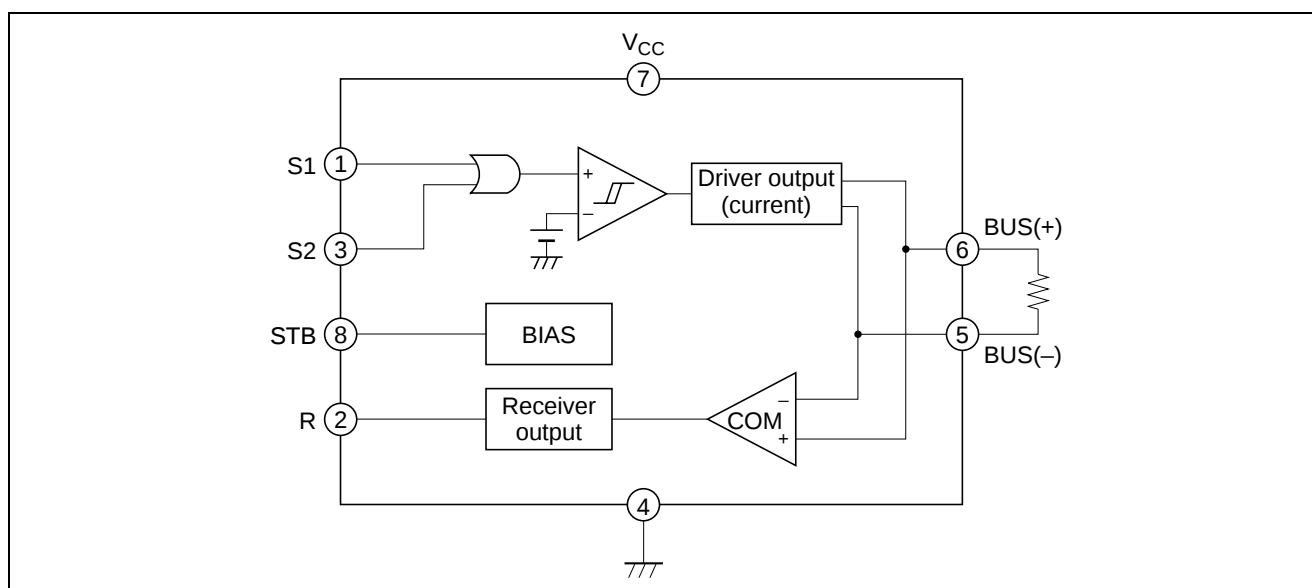
Functions

- Two-input OR circuit
- Input comparator circuit (3.3 V and 5.0 V available)
- Current output driver circuit
- Receiver input comparator circuit
- Receiver output circuit (Open-collector output)
- Standby circuit

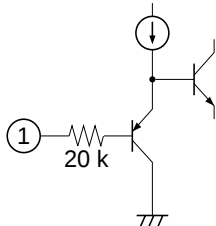
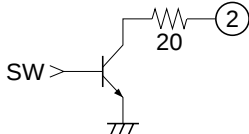
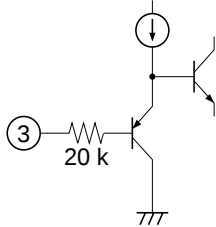
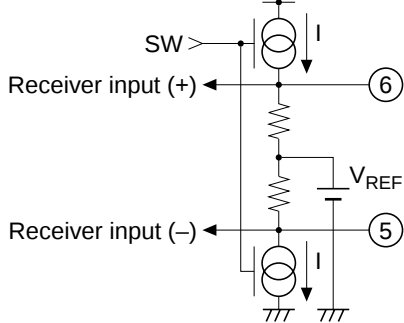
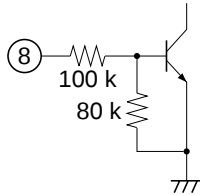
Features

- Supports two data inputs (Pins 1 and 3 are the input pins)
- Comparators with hysteresis characteristics are adopted for the inputs (3.3 V and 5.0 V available)
- Current drive output drivers adopted (Output current: 3.8 mA typical)
- Comparators with hysteresis characteristics are adopted for the receivers
- Wide receiver common-mode input operating range (Common-mode input operating range: 0 to 5 V typical)
- The driver output /the receiver input (pins 5 and 6) can withstand high voltages (Maximum ratings of 18 V)
- Standby functions (standby mode when pin 8 becomes low level)
- Operating power-supply voltage range of 5 V $\pm$ 0.5 V

Block Diagram



Pin Functions

Pin No.	Symbol	Function	Equivalent Circuit
1	S1	Data input pin 1	
2	R	Receiver output pin	
3	S2	Data input pin 2	
4	GND	GND pin	
5	BUS(-)	Bus output (-), Receiver input (-) pin	
6	BUS(+)	Bus output (+), Receiver input (+) pin	
7	V _{CC}	Power supply pin	
8	STB	Standby input pin (Lo: ON, Hi: OFF)	

Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Ratings	Unit	Note
Power-supply voltage	V _{CC}	7	V	
Input voltage	V _{IN}	GND–0.3 to V _{CC} +0.3	V	
Bus input voltage	V _{bus}	18	V	
Allowable power dissipation	P _d	400	mW	Ta ≤ 85°C
Operating temperature	T _{opr}	–40 to +85	°C	
Storage temperature	T _{stg}	–55 to +125	°C	

Note: Recommended operating power supply voltage range: 5 V ± 0.5 V

Electrical Characteristics

(V_{CC} = 5.0 V, Ta = 25°C)

Item		Symbol	Min	Typ	Max	Unit	Test Conditions	Test Pin	Test Circuit
S1	High-level input voltage	V _{IHS1}	2.1	—	—	V	V1 = 0→5 V, V3 = 0 V, V6 – V5 = 110 mV↑	1	Fig. 1
	Low-level input voltage	V _{ILS1}	—	—	1.65	V	V1 = 5→0 V, V3 = 0 V, V6 – V5 = 30 mV↓	1	
	High-level input current	I _{IHS1}	—	—	1	μA	V1 = 5 V, V3 = 0 V	1	
	Low-level input current	I _{ILS1}	—	—	1	μA	V1 = 0 V, V3 = 0 V	1	
S2	High-level input voltage	V _{IHS2}	2.1	—	—	V	V3 = 0→5 V, V1 = 0 V, V6 – V5 = 110 mV↑	3	Fig. 1
	Low-level input voltage	V _{ILS2}	—	—	1.65	V	V3 = 5→0 V, V1 = 0 V, V6 – V5 = 30 mV↓	3	
	High-level input current	I _{IHS2}	—	—	1	μA	V1 = 0 V, V3 = 5 V	3	
	Low-level input current	I _{ILS2}	—	—	1	μA	V1 = 0 V, V3 = 0 V	3	
Driver	High-level output voltage (+)	V _{OHD+}	1.8	2.5	3.2	V	V1 = 5 V, V3 = 0 V	6	Fig. 1
	High-level output voltage (–)	V _{OHD–}	1.8	2.5	3.2	V	V1 = 5 V, V3 = 0 V	5	
	High-level output current	I _{OH}	3.1	3.8	4.5	mA	V1 = 5 V, V3 = 0 V, I _{OH} = ((V _{OHD+}) – (V _{OHD–}))/60	5, 6	
	Low-level output current	I _{OL}	—	—	1	μA	V1 = 0 V, V3 = 0 V, I _{OL} = ((V _{OP+}) – (V _{OP–}))/R _i	5, 6	
Reference operating voltage (+)		V _{OP+}	2.3	2.5	2.7	V	V1 = 0 V, V3 = 0 V	6	Fig. 1
Reference operating voltage (–)		V _{OP–}	2.3	2.5	2.7	V	V1 = 0 V, V3 = 0 V	5	Fig. 1
Driver output resistance * ¹		R _O	5	10	15	kΩ	V1 = 5 V, V3 = 0 V, V8 = 5 V, R _O = 0.6 V/(I6A – I6B)		Fig. 3

Note: 1. Measure the current when V6 = (V_{OP+}) + 0.3 V to make I_{6A} and measure the current when V6 = (V_{OP+}) – 0.3 V to make I_{6B}.

Electrical Characteristics (cont.)

(V_{CC} = 5.0 V, T_a = 25°C)

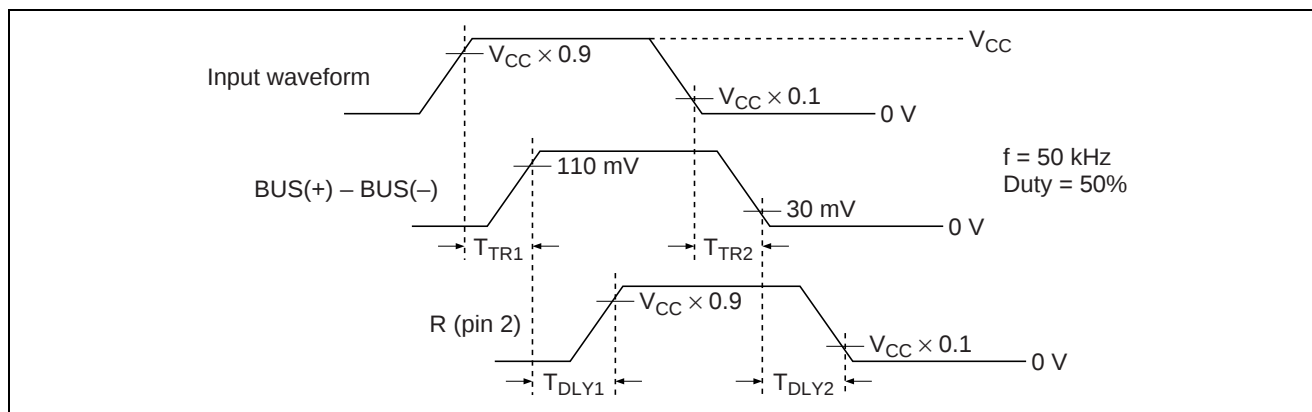
Item		Symbol	Min	Typ	Max	Unit	Test Conditions	Test Pin	Test Circuit
Receiver	High-level input voltage (1)	V _{IH1}	—	80	110	mV	V6 = 0→5 V, Pin2 = 4 V or more, V1 = 0 V, V3 = 0 V, V5 = 0 V, V _{IH1} = V6 – V5	2	Fig. 2
	High-level input voltage (2)	V _{IH2}	—	80	110	mV	V6 = 0→5 V, Pin2 = 4 V or more, V1 = 0 V, V3 = 0 V, V5 = 4.5 V, V _{IH2} = V6 – V5	2	
	Low-level input voltage (1)	V _{IL1}	30	50	—	mV	V6 = 5→0 V, Pin2 = 1 V or less, V1 = 0 V, V3 = 0 V, V5 = 0 V, V _{IL1} = V6 – V5	2	
	Low-level input voltage (2)	V _{IL2}	30	50	—	mV	V6 = 5→0 V, Pin2 = 1 V or less, V1 = 0 V, V3 = 0 V, V5 = 4.5 V, V _{IL2} = V6 – V5	2	
	Input hysteresis voltage (1)	V _{IHYS1}	15	30	45	mV	V _{IHYS1} = V _{IH1} – V _{IL1}		
	Input hysteresis voltage (2)	V _{IHYS2}	15	30	45	mV	V _{IHYS2} = V _{IH2} – V _{IL2}		
	High-level common-mode input voltage	V _{IHCOM}	4.5	—	—	V	V5 = 0→5 V, V5 when pin2 = 4 V or less, V1 = 0 V, V3 = 0 V, V6 – V5 = 110 mV	5	Fig. 2
	Low-level common-mode input voltage	V _{ILCOM}	5	—	—	V	V5 = 0→5 V, V5 when pin2 = 0.3 V or more, V1 = 0 V, V3 = 0 V, V6 – V5 = 30 mV	5	
	Input resistance ^{*1}	R _I	25	35	45	kΩ	V1 = 0 V, V3 = 0 V, V8 = 5 V, R _I = 0.6 V/(I6A – I6B)	5, 6	Fig. 3
	High-level output leakage current 1	I _{OH1}	—	—	1	μA	V1 = 5 V, V3 = 0 V, V8 = 5 V	2	Fig. 1
	High-level output leakage current 2	I _{OH2}	—	—	1	μA	V _{CC} = 0 V, V1,V3,V8 = 0 V	2	
	High-level output leakage current 3	I _{OH3}	—	—	1	μA	V1,V3,V8 = 0 V	2	
	Low-level output voltage 1	V _{OL1}	—	—	0.6	V	V1 = 0 V, V3 = 0 V, V8 = 5 V, Adjust V _{RL} to make apply current = 1.5 mA	2	
	Low-level output voltage 2	V _{OL2}	—	—	0.3	V	V1 = 0 V, V3 = 0 V, V8 = 5 V, Adjust V _{RL} to make apply current = 200 μA	2	
		Quiescent current 1	I _{CC} H	4.5	6.5	8.5	mA	V1 = 5 V, V3 = 0 V	7
	Quiescent current 2	I _{CC} L	1.05	1.46	1.87	mA	V1 = 0 V, V3 = 0 V	7	Fig. 1
	Driver delay time (L→H)	T _{TR1}	—	100	300	ns	See operating waveform figure	5, 6	Fig. 5
	Driver delay time (H→L)	T _{TR2}	—	100	300	ns	See operating waveform figure	5, 6	
	Receiver delay time (L→H)	T _{DLY1}	—	600	1200	ns	See operating waveform figure	2	
	Receiver delay time (H→L)	T _{DLY2}	—	200	600	ns	See operating waveform figure	2	

Note: 1. Measure the current when V6 = (V_{OP+}) + 0.3 V to make I6A and measure the current when V6 = (V_{OP+}) – 0.3 V to make I6B.

Electrical Characteristics (cont.)

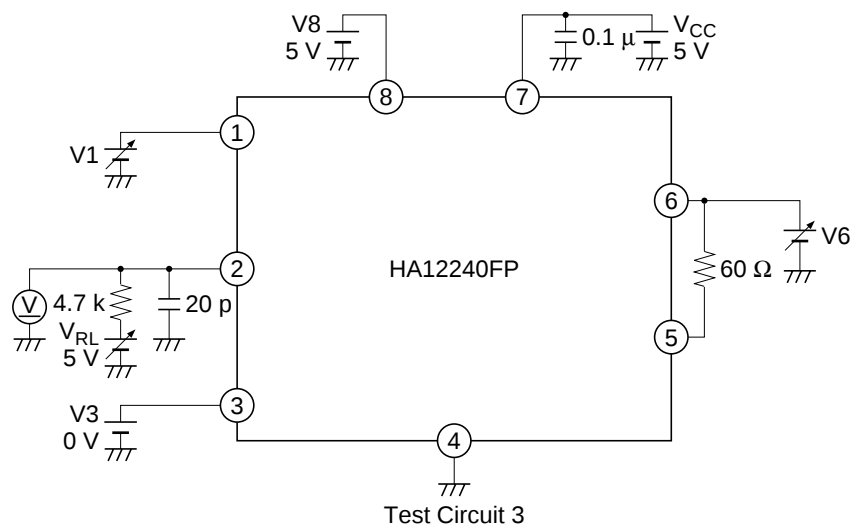
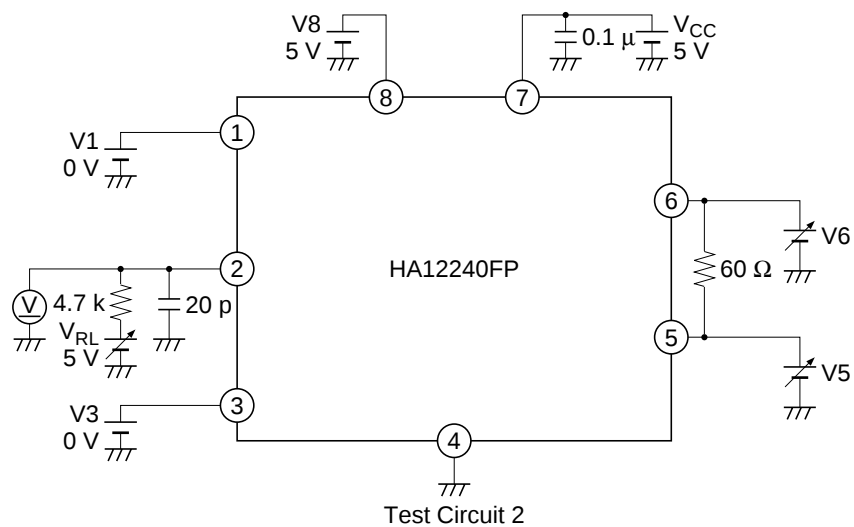
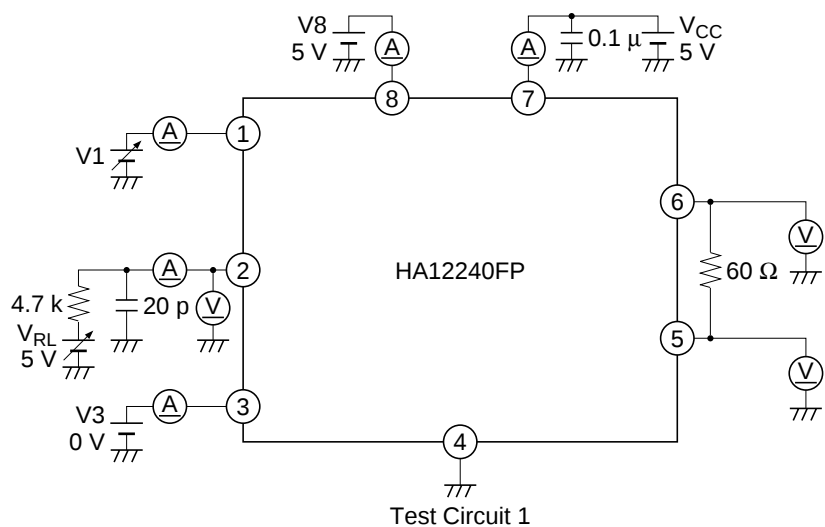
(V_{CC} = 5.0 V, T_a = 25°C)

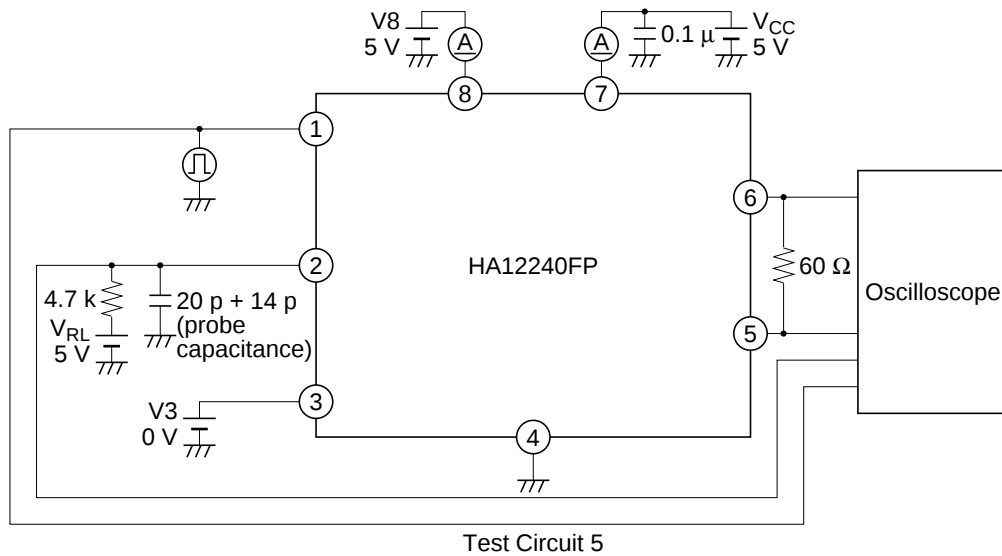
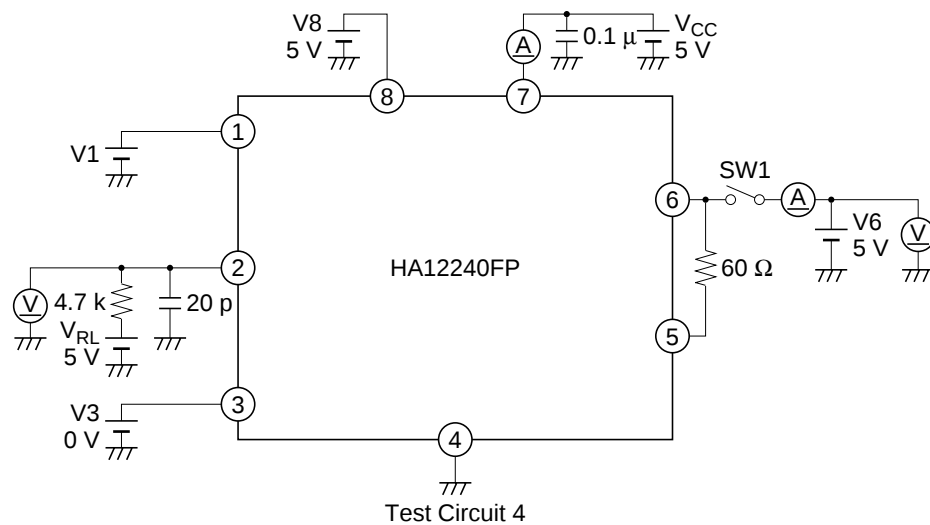
Item	Symbol	Min	Typ	Max	Unit	Test Conditions	Test Pin	Test Circuit
Power-supply off output leakage current	I _{OLEAK}	—	—	1	μA	V _{CC} = 0 V, V ₈ = 0 V, V ₆ = 5 V, V ₁ = 0 V, V ₃ = 0 V, SW1 ON	6	Fig. 4
Standby mode current drain	I _{CCstb}	—	—	1	μA	V ₁ = 5 V, V ₃ = 0 V, V ₈ = 0 V	7	Fig. 4
Standby mode output leakage current	I _{stb-Leak}	—	—	1	μA	V ₁ = 5 V, V ₃ = 0 V, V ₈ = 0 V, V ₆ = 5 V, SW1 ON	6	Fig. 4
Standby mode high-level input voltage	V _{stbH}	2	—	—	V	V ₈ = 0→5 V, V ₈ when pin5,6 = 2.3 V or more, V ₁ = 0 V, V ₃ = 0 V	8	Fig. 1
Standby mode low-level input voltage	V _{stbL}	—	—	0.9	V	V ₈ = 5→0 V, V ₈ when current flowing into pin7 = 1 μA or less, V ₁ = 5 V, V ₃ = 0 V	8	Fig. 1
Standby mode high-level input current	I _{stbH}	—	50	100	μA	V ₁ = 5 V, V ₃ = 0 V, V ₈ = 5 V	8	Fig. 1
Standby mode low-level input current	I _{stbL}	—	—	1	μA	V ₁ = 5 V, V ₃ = 0 V, V ₈ = 0 V	8	Fig. 1



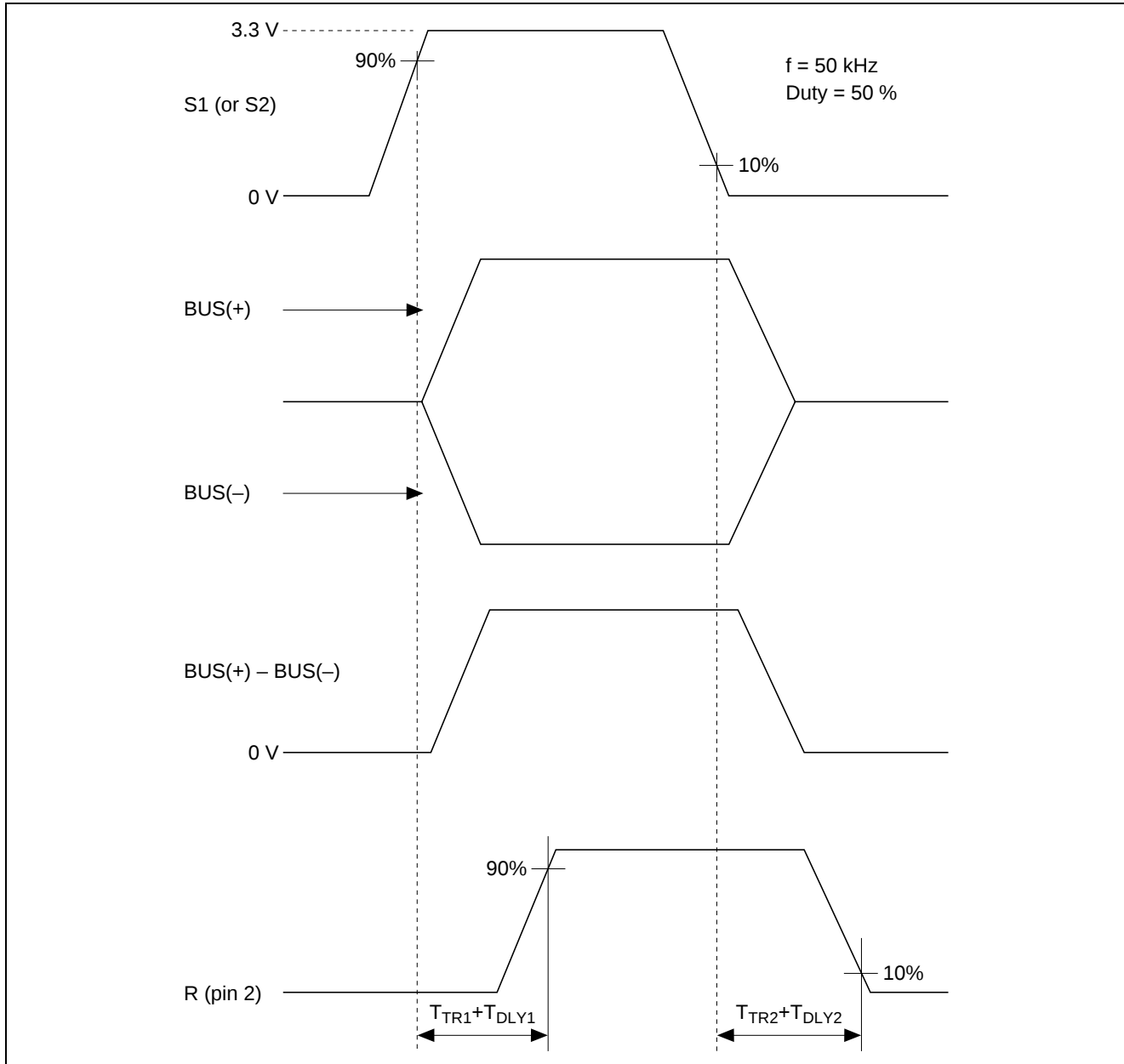
Input/Output Waveform Figure

Test Circuits

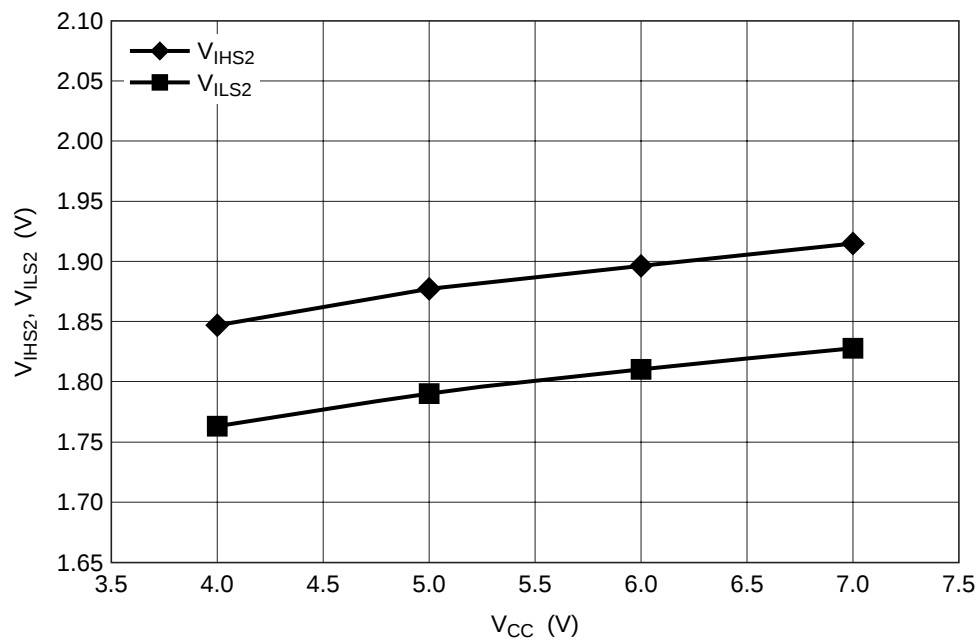
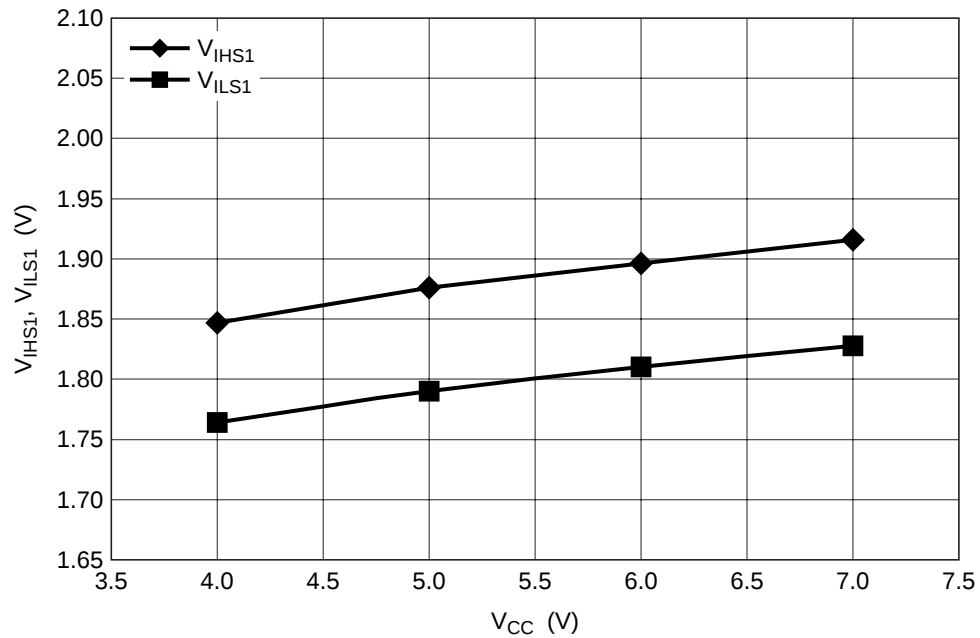


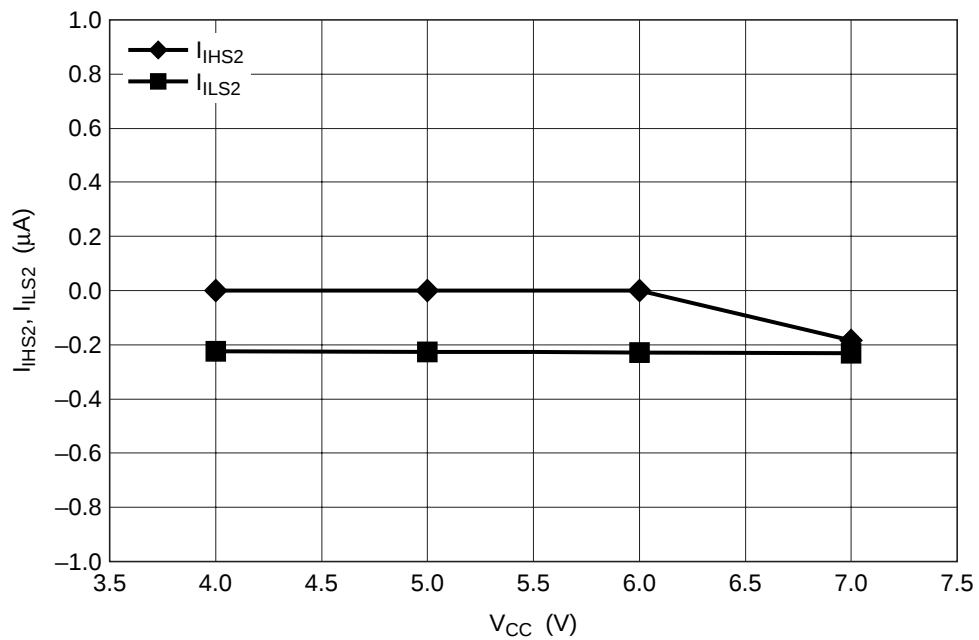
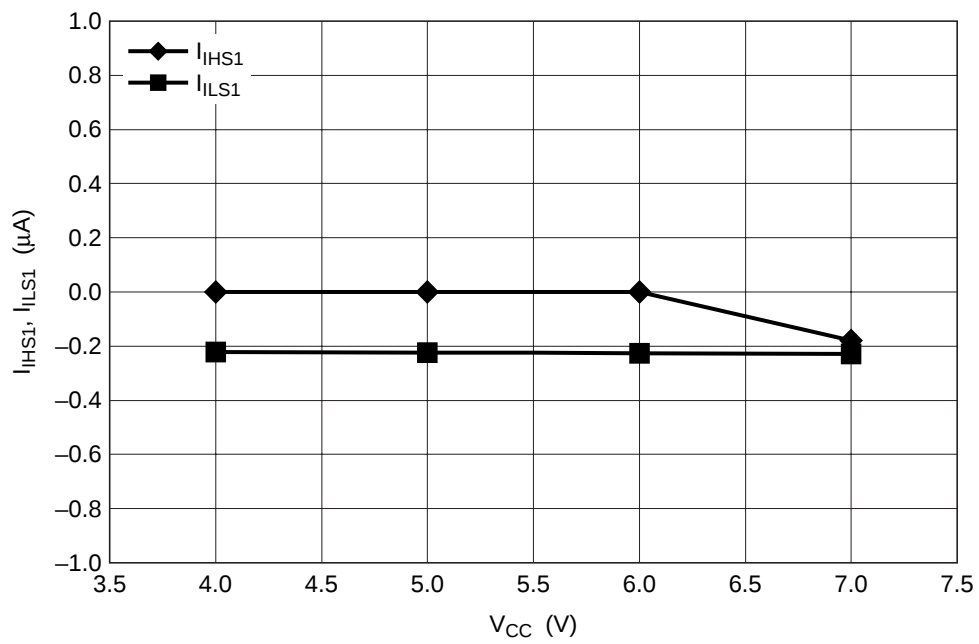


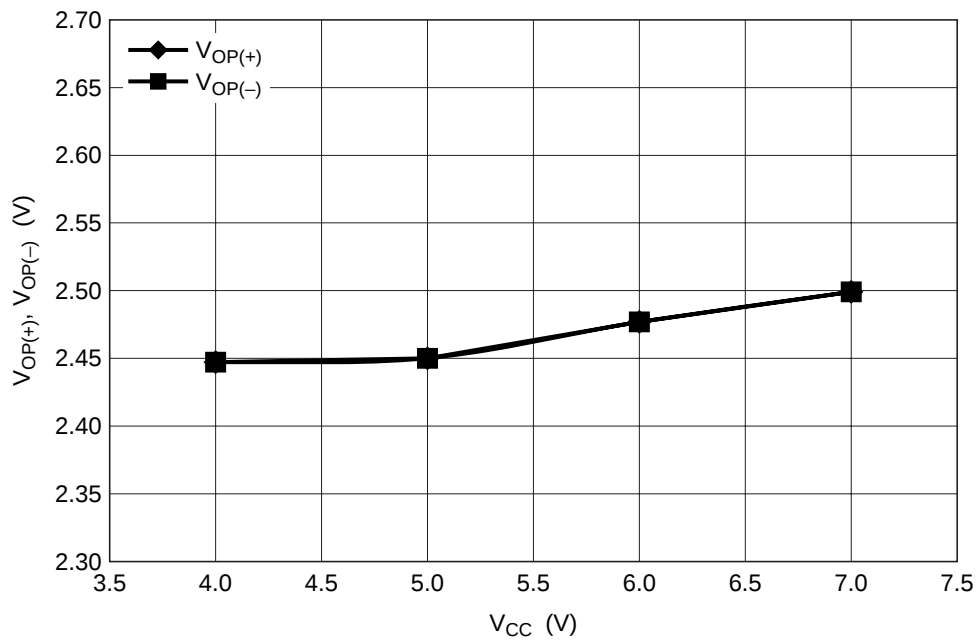
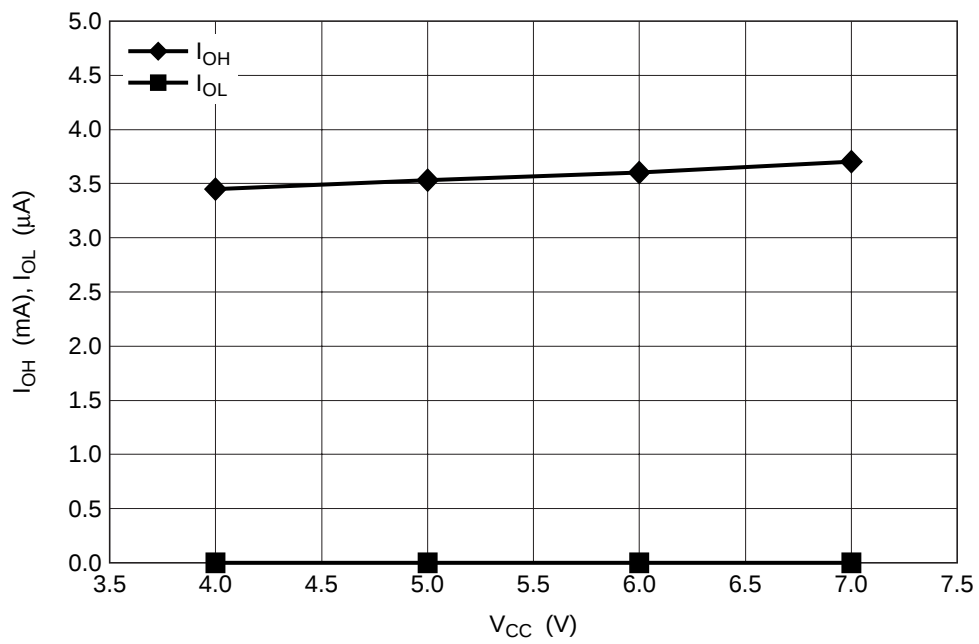
Operating Waveforms

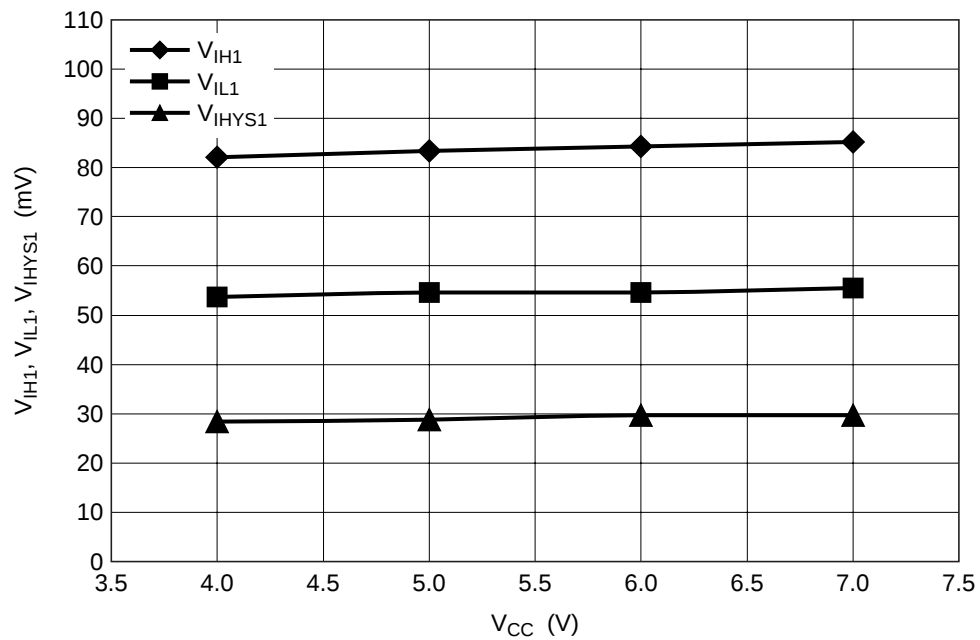
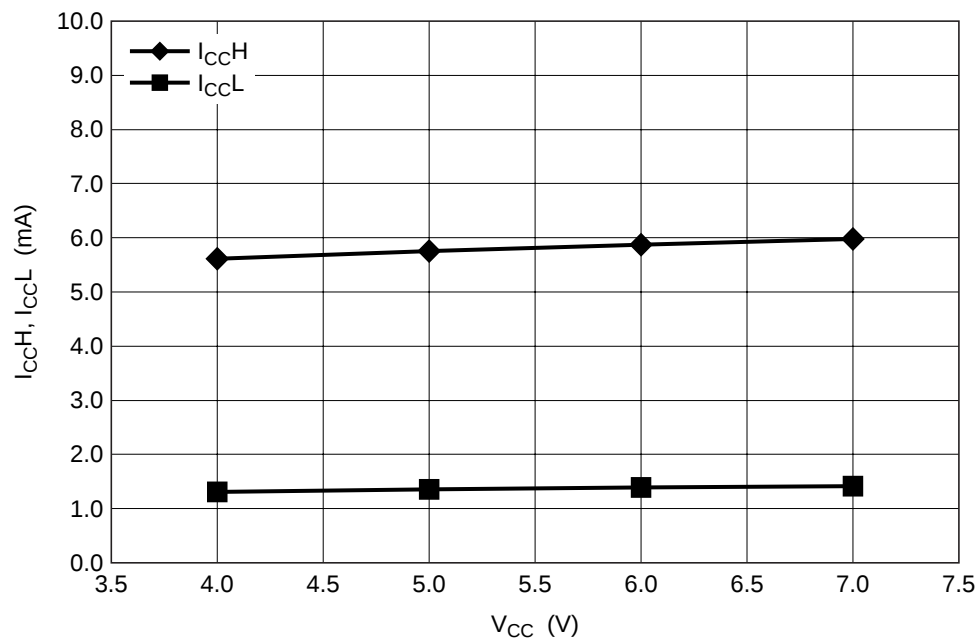


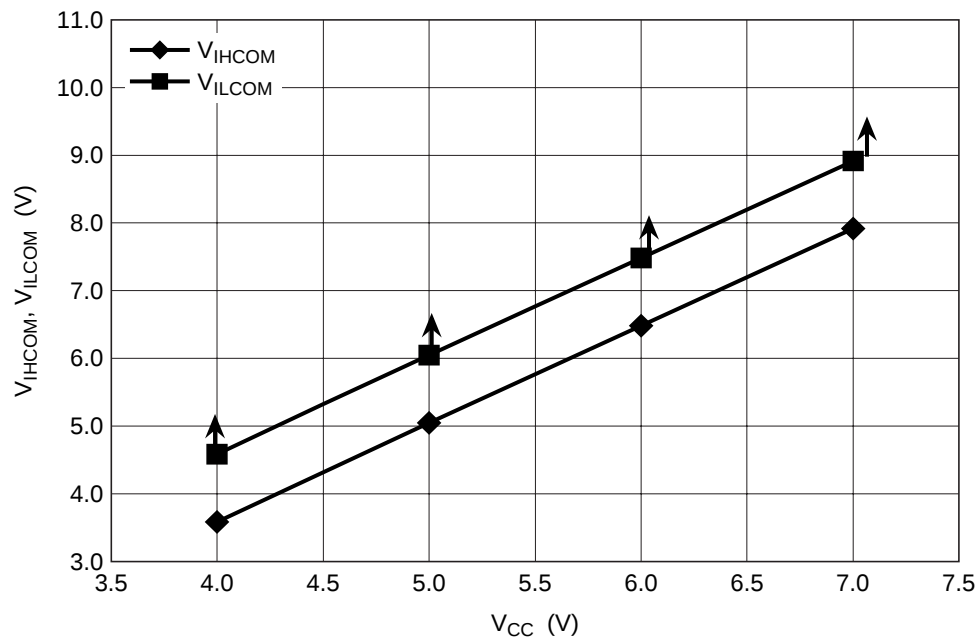
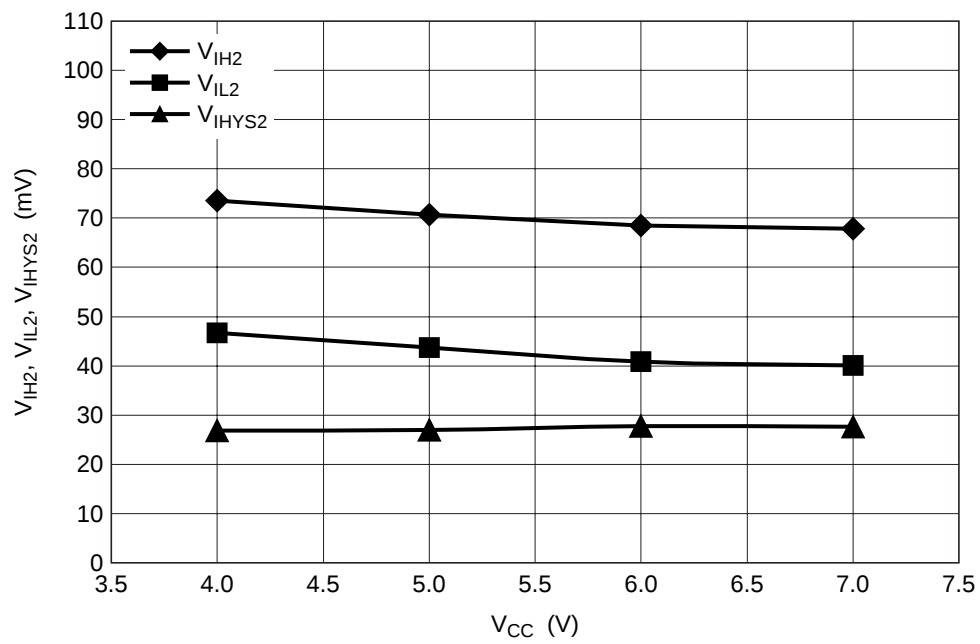
Main Characteristics

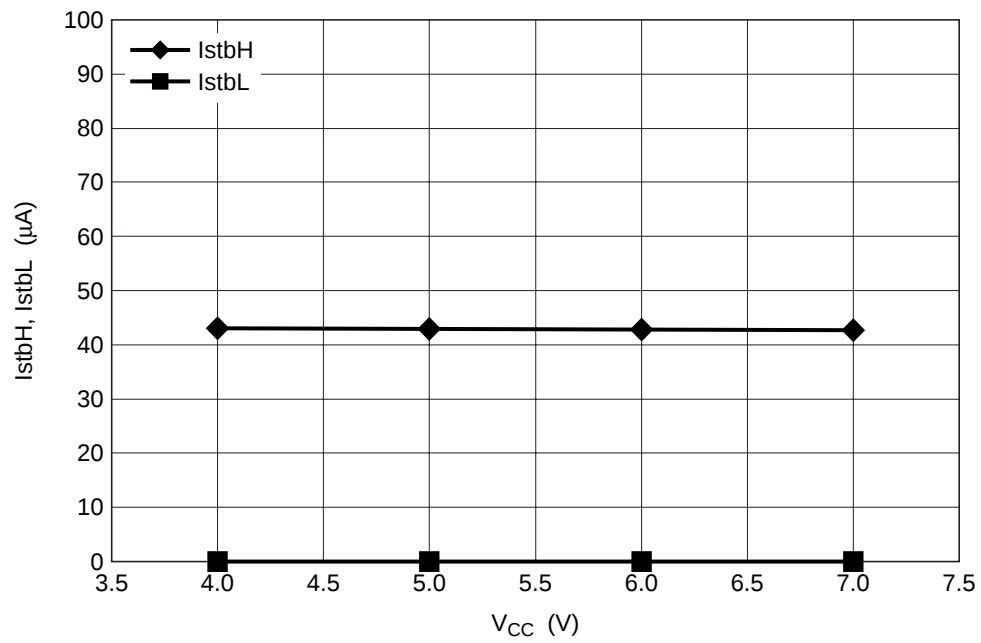
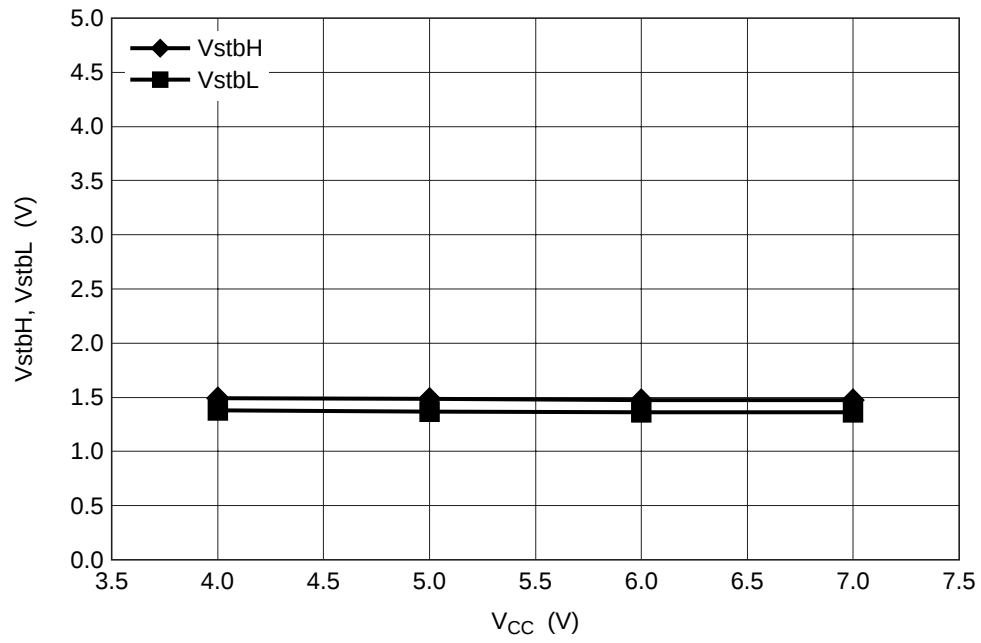


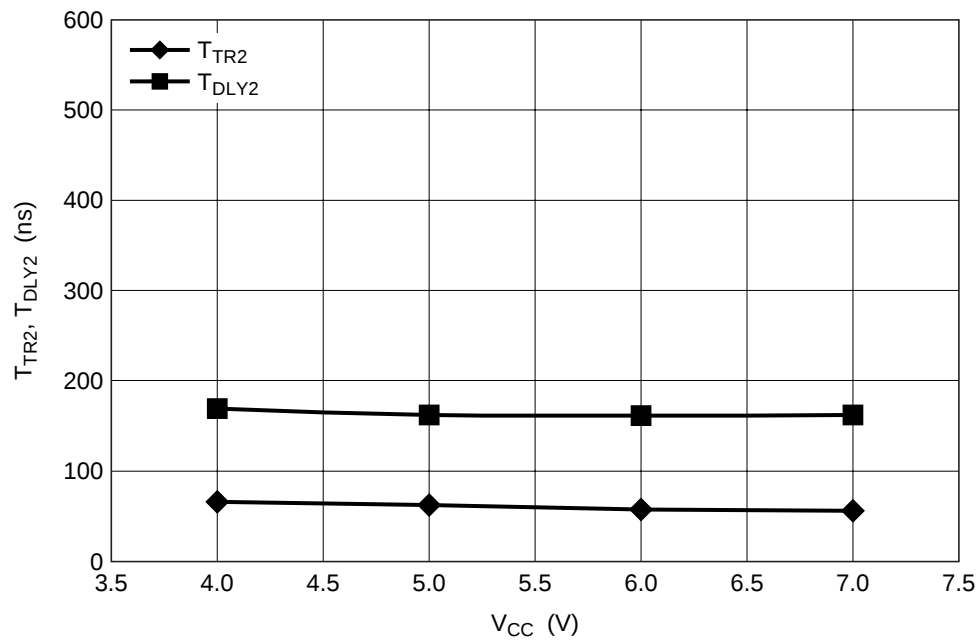
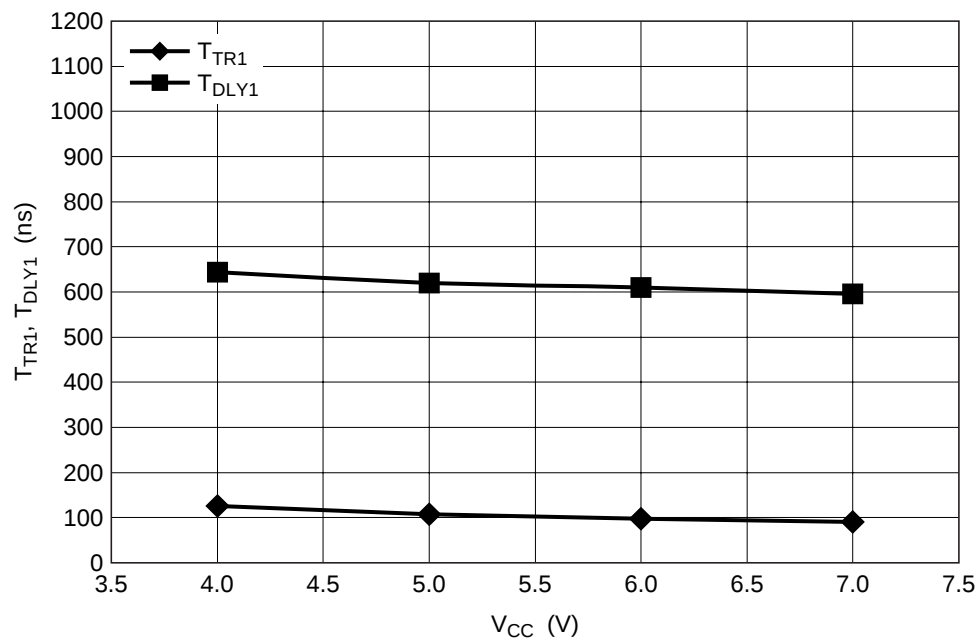


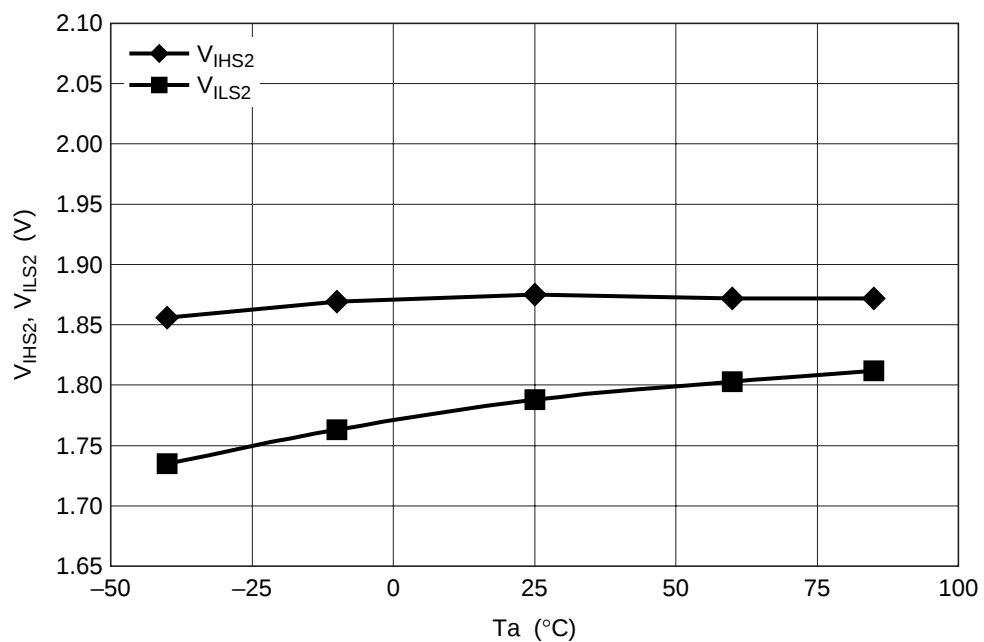
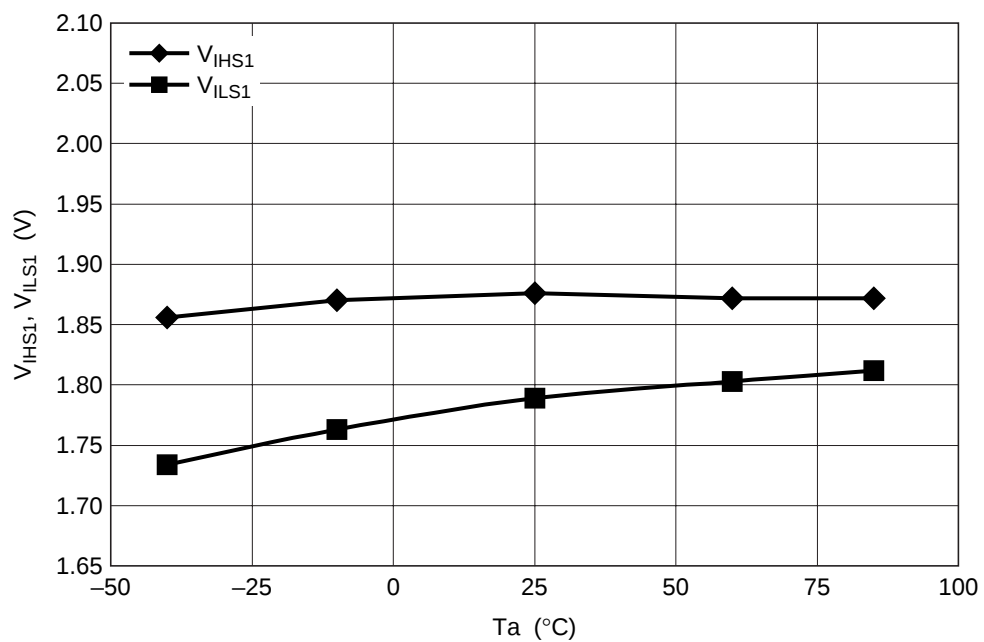


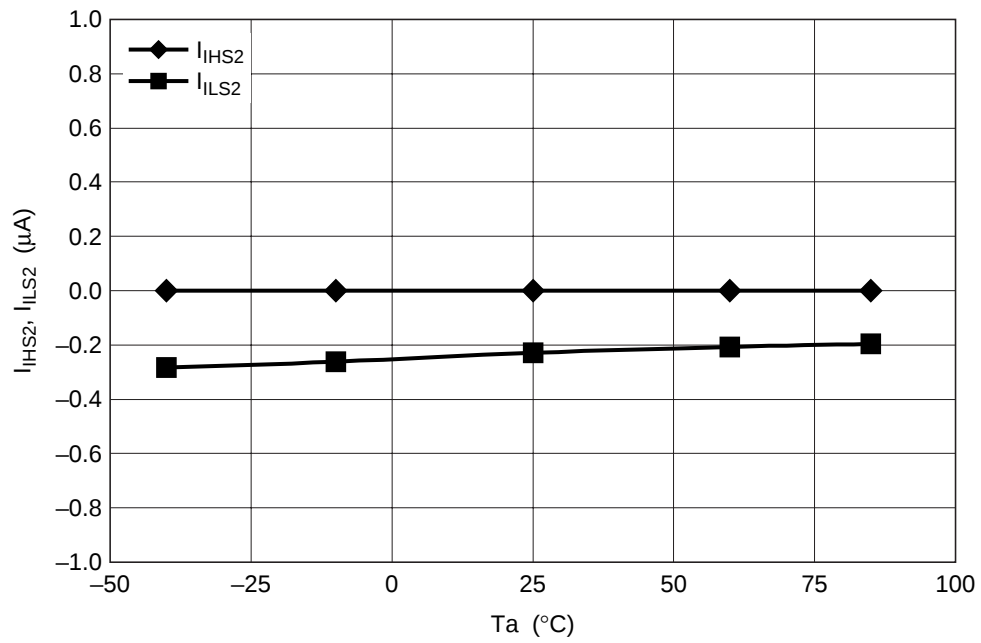
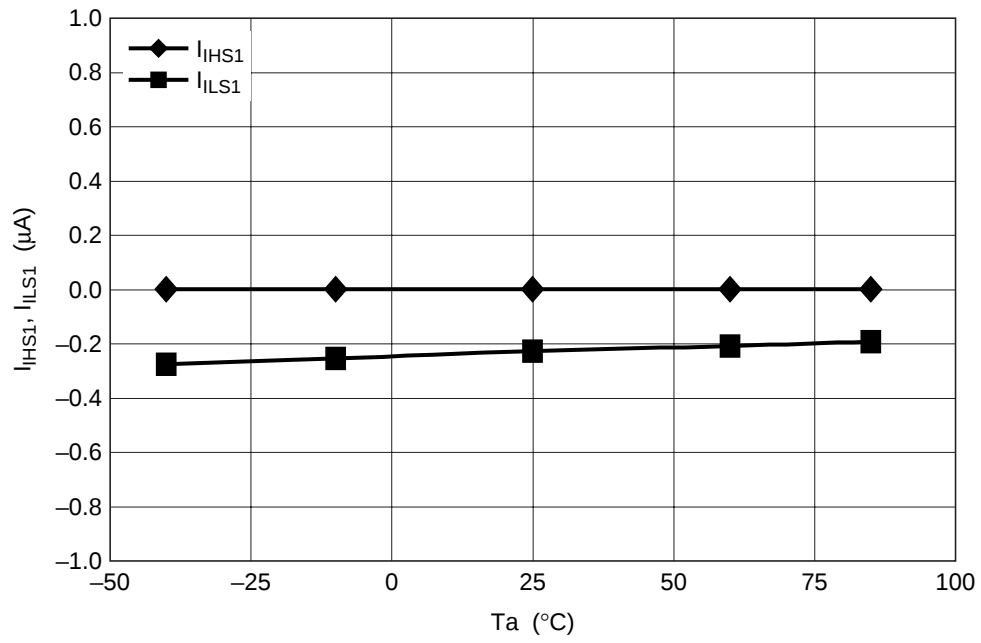


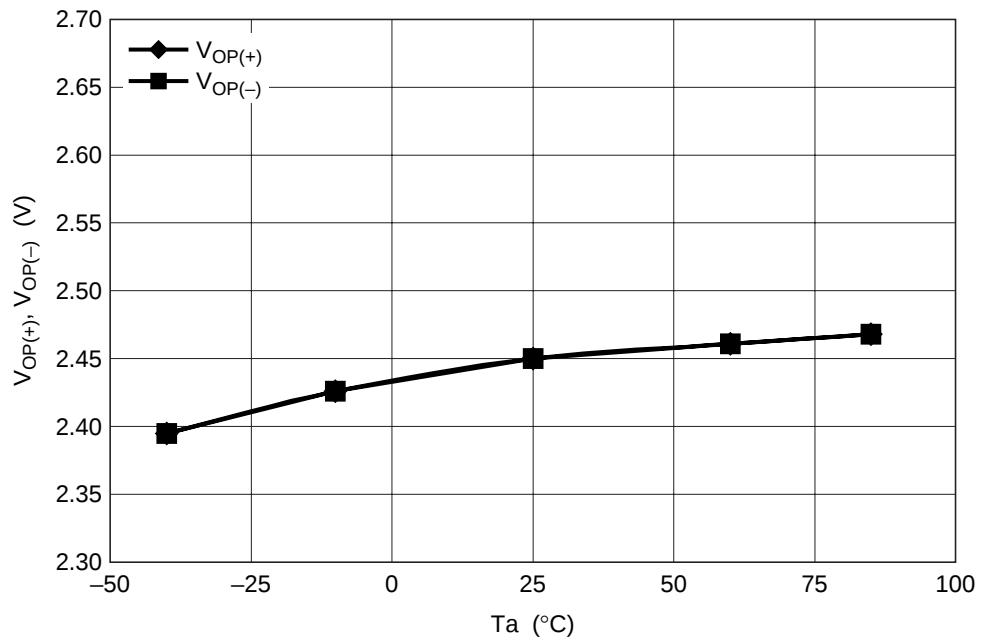
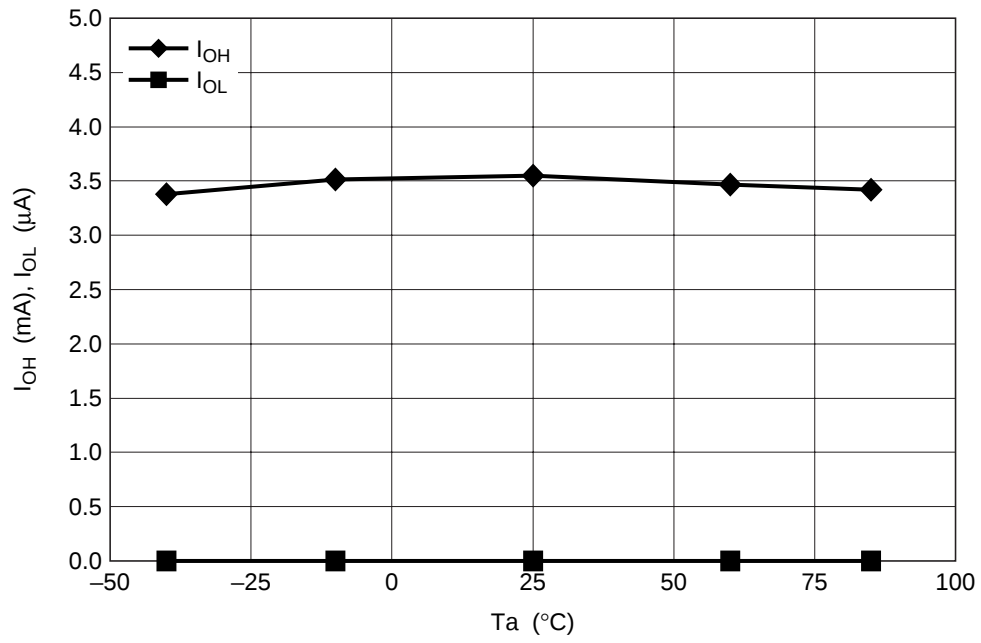


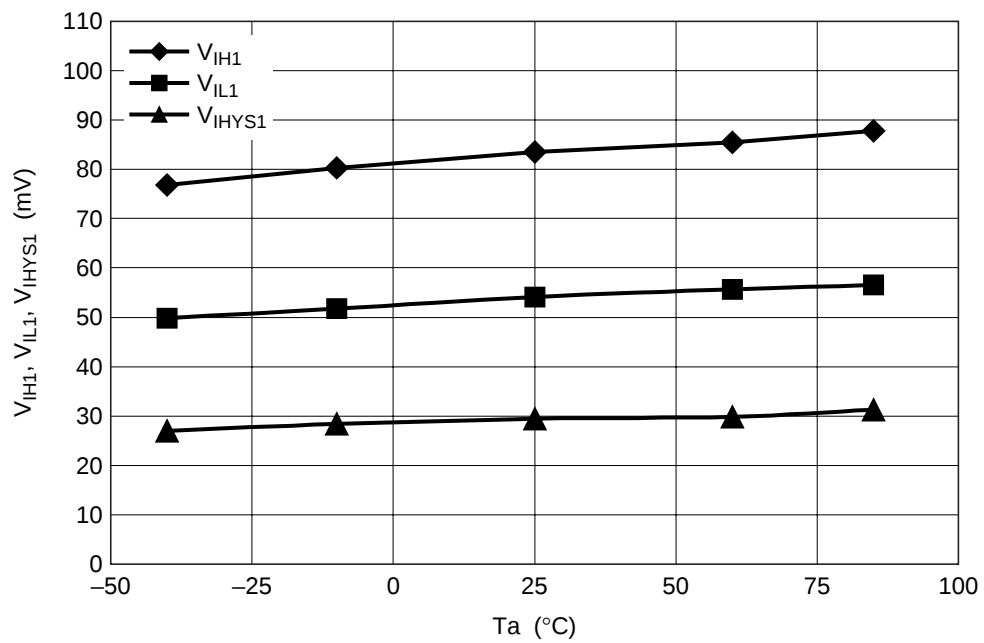
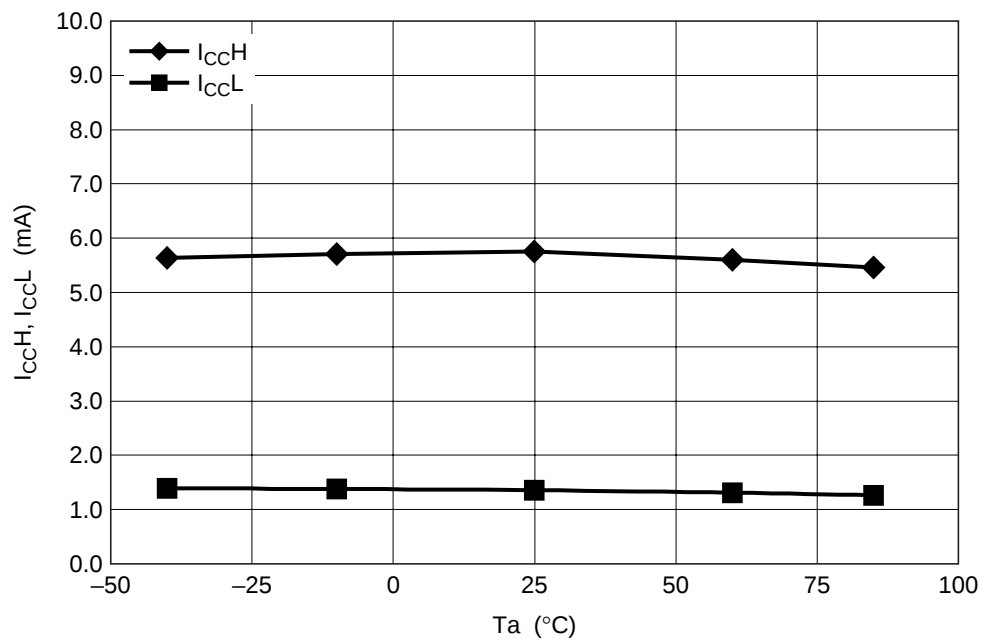


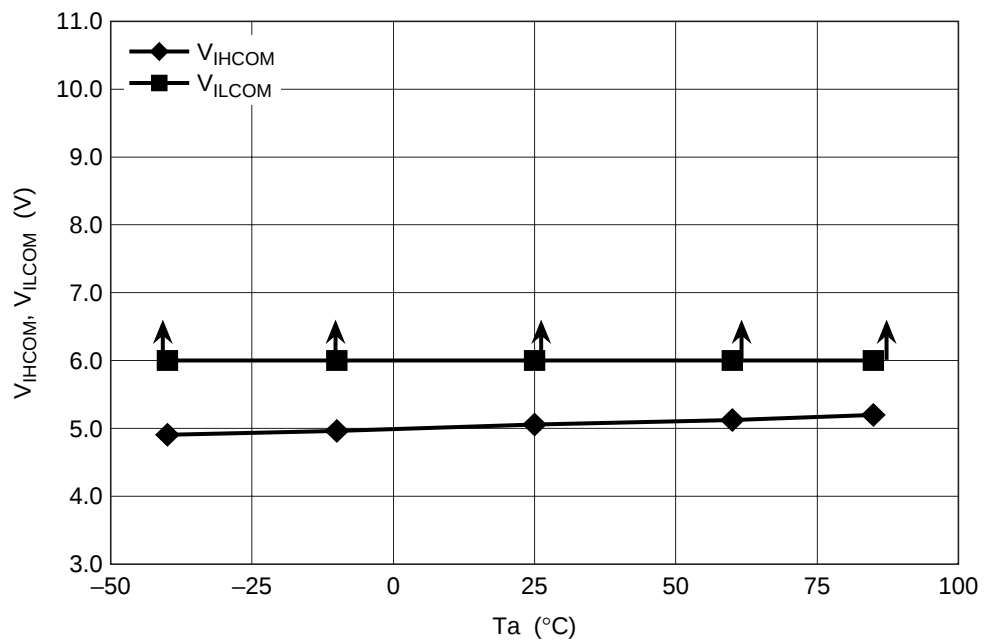
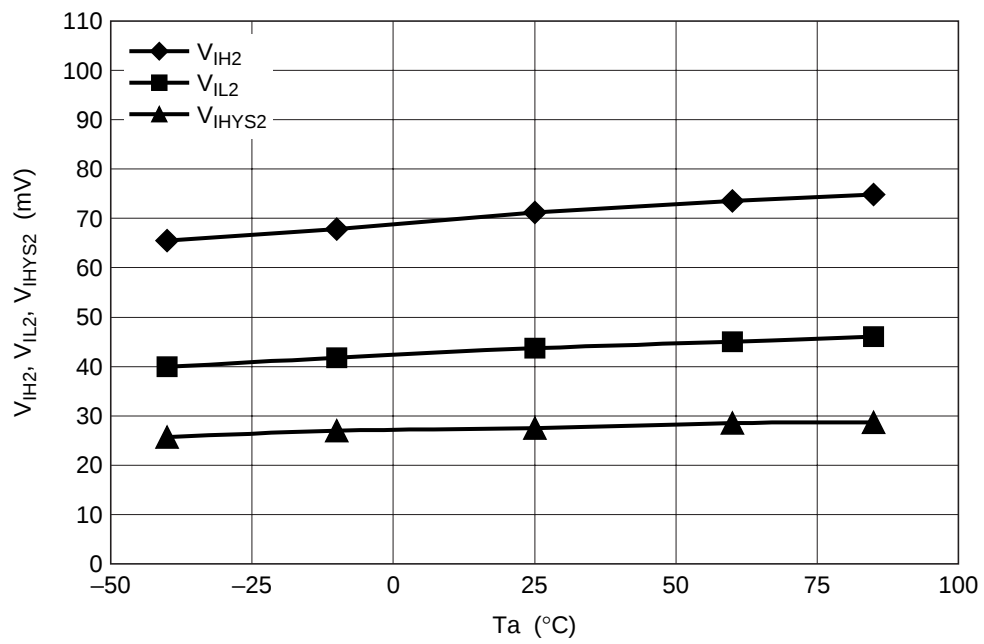


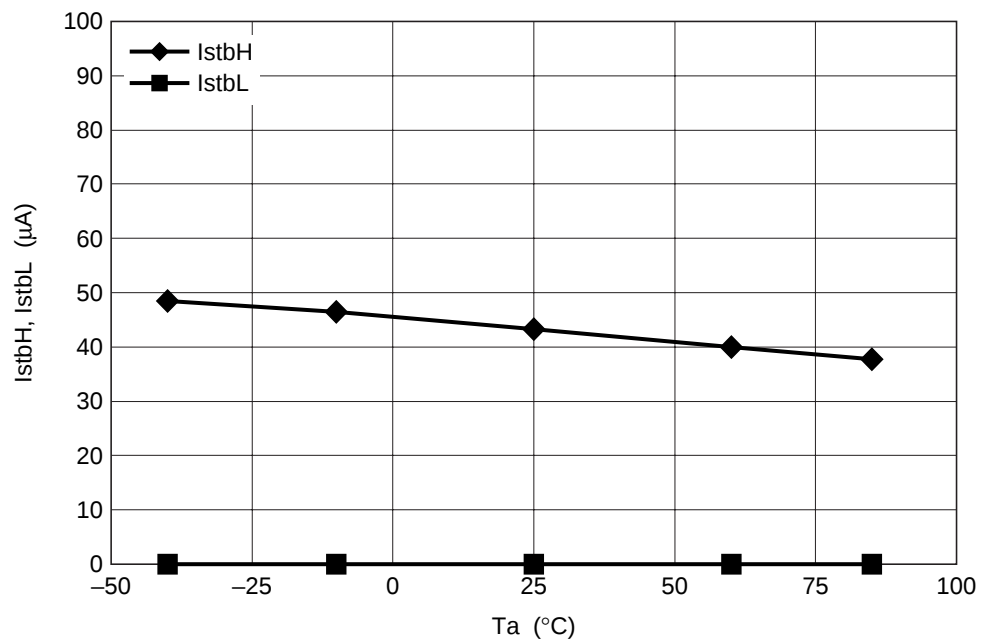
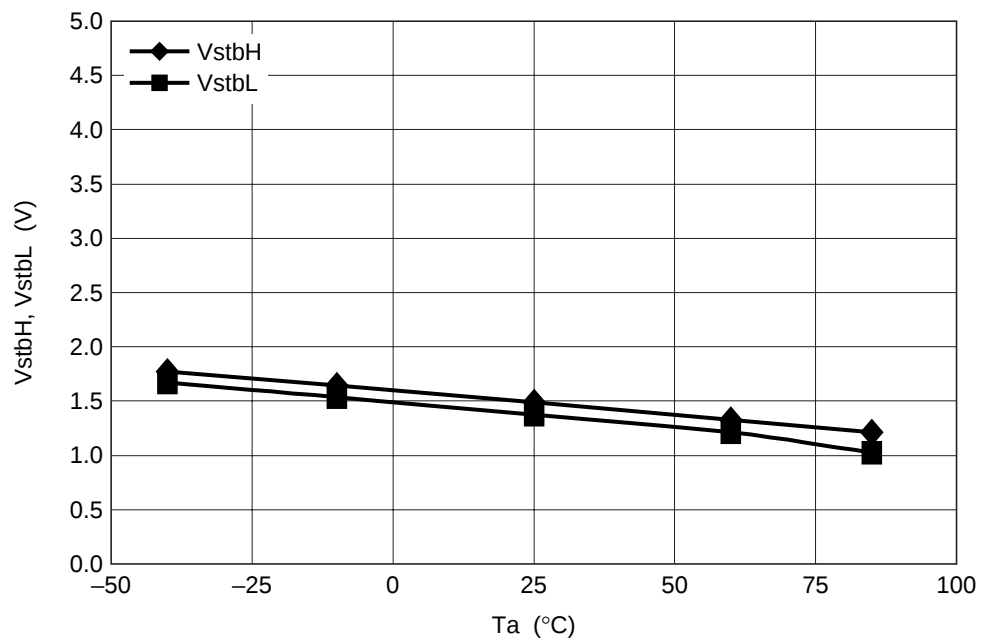


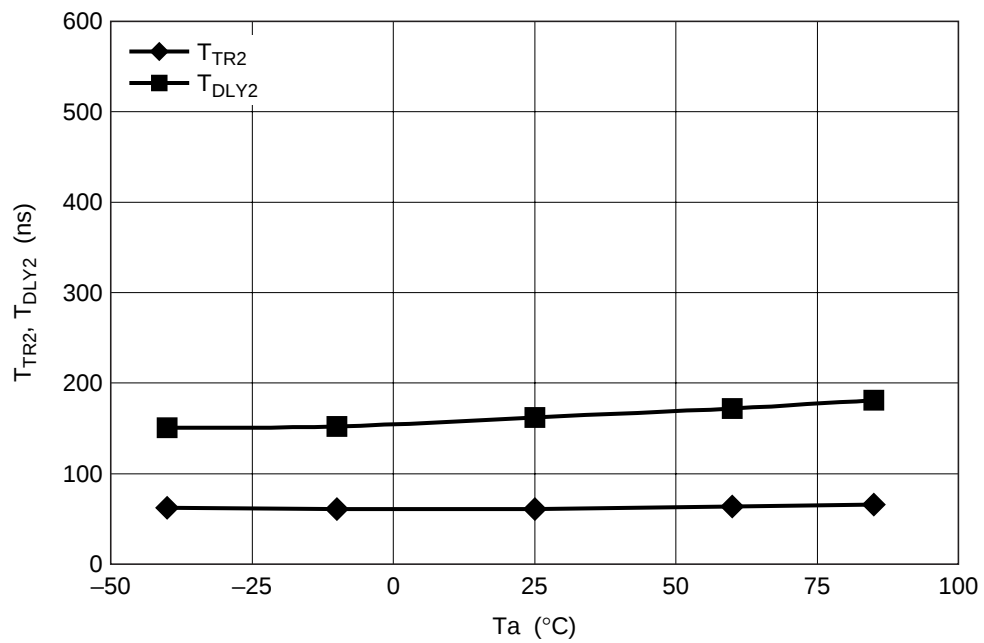
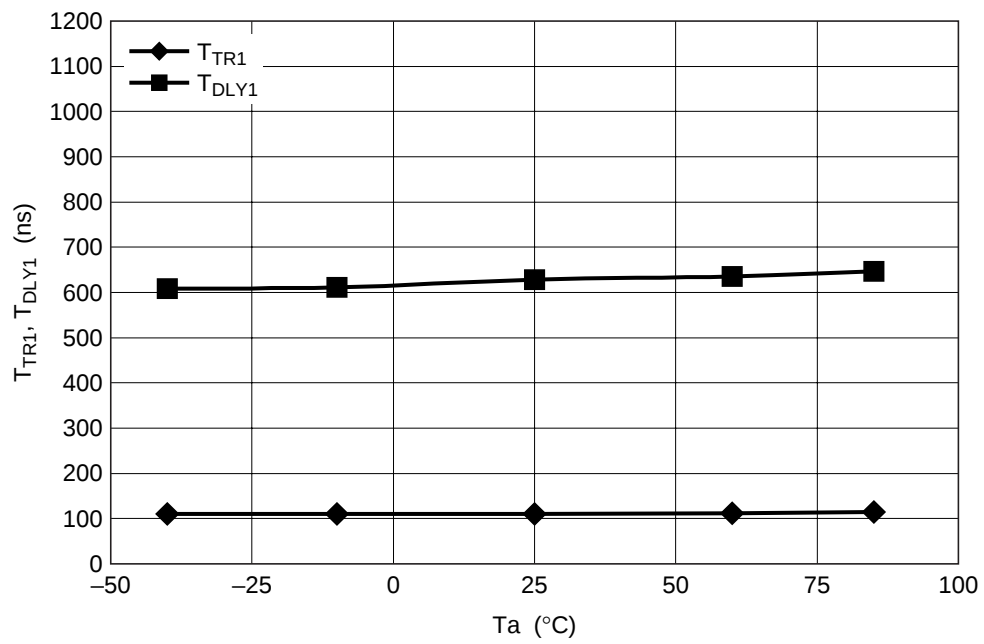






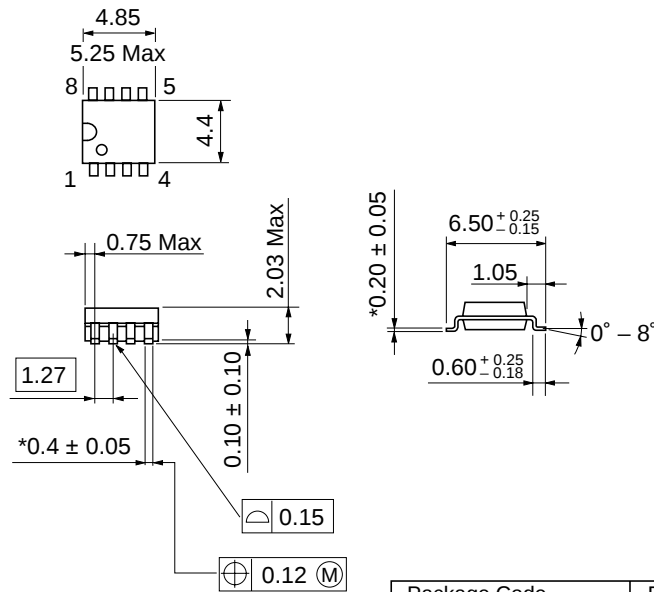






Package Dimensions

Unit: mm



*Dimension including the plating thickness

Package Code	FP-8DGV
JEDEC	—
JEITA	Conforms
Mass (reference value)	0.10 g

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